UNITED STATES PATENT AND TRADEMARK OFFICE **CERTIFICATE OF CORRECTION**

PATENT NO.

: 6,979,855 B2

DATED

: December 27, 2005

INVENTOR(S) : Ahn et al.

Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Title page,

Item [56], References Cited, U.S. PATENT DOCUMENTS, after "Ahn" delete "et al. 29/76"; delete "Vaarstra" and insert -- Vaartstra --; delete "2005/0026456" and insert -- 2005/0026458 --.

OTHER PUBLICATIONS,

"Giess, E. A., et al.," reference, delete "IMB" and insert -- IBM --.

"Jeon, Sanghun, et al.," reference, after "oxide and" delete "lathanide" and insert

-- lanthanide -- and delete "Internationa," and insert -- International, --.

"Liu, C.T.," reference, delete "Internation" and insert -- International --.

"Saito, Yuji, et al.," reference, delete "Ktypton" and insert -- Krypton --.

Signed and Sealed this

Twenty-first Day of March, 2006

JON W. DUDAS Director of the United States Patent and Trademark Office